

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

**TC74HC4051AP,TC74HC4051AF,TC74HC4051AFT**  
**TC74HC4052AP,TC74HC4052AF,TC74HC4052AFT**  
**TC74HC4053AP,TC74HC4053AF,TC74HC4053AFT**

**TC74HC4051AP/AF/AFT**

8-Channel Analog Multiplexer/Demultiplexer

**TC74HC4052AP/AF/AFT**

Dual 4-Channel Analog Multiplexer/Demultiplexer

**TC74HC4053AP/AF/AFT**

Triple 2-Channel Analog Multiplexer/Demultiplexer

The TC74HC4051A/4052A/4053A are high speed CMOS ANALOG MULTIPLEXER/DEMULTIPLEXER fabricated with silicon gate C<sup>2</sup>MOS technology. They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC4051A has an 8 channel configuration, the TC74HC4052A has a 4 channel × 2 configuration and the TC74HC4053A has a 2 channel × 3 configuration.

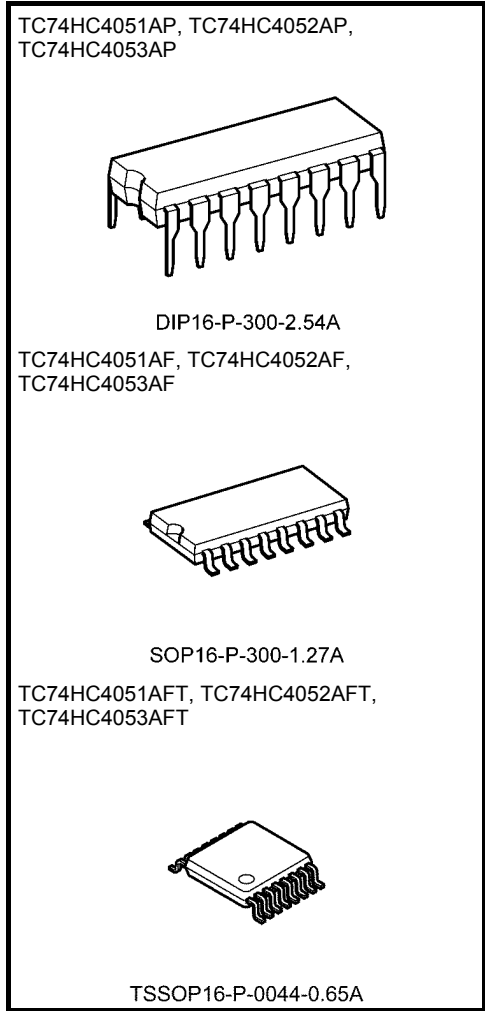
The digital signal to the control terminal turns “ON” the corresponding switch of each channel a large amplitude signal (V<sub>CC</sub> – V<sub>EE</sub>) can then be switched by the small logical amplitude (V<sub>CC</sub> – GND) control signal.

For example, in the case of V<sub>CC</sub> = 5 V, GND = 0 V, V<sub>EE</sub> = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with a single power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuits with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

**Features**

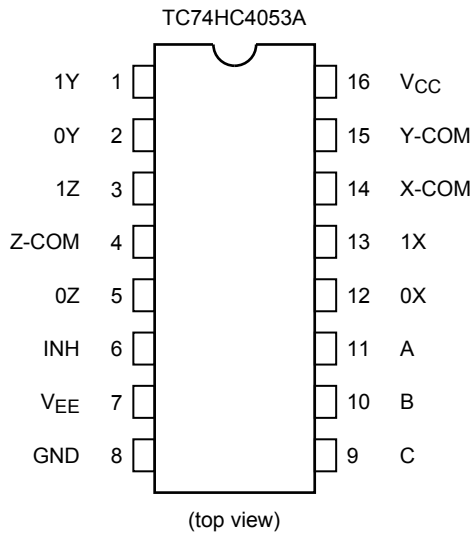
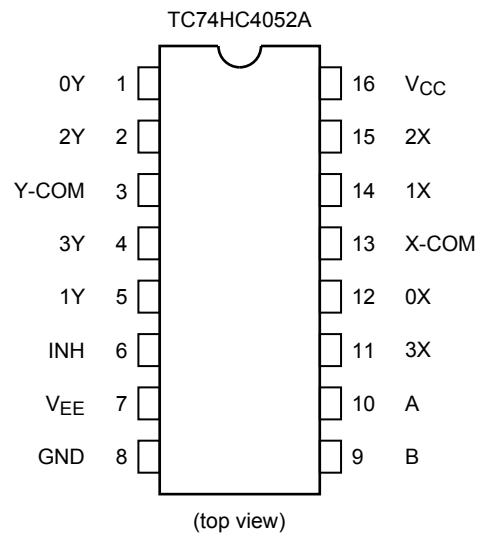
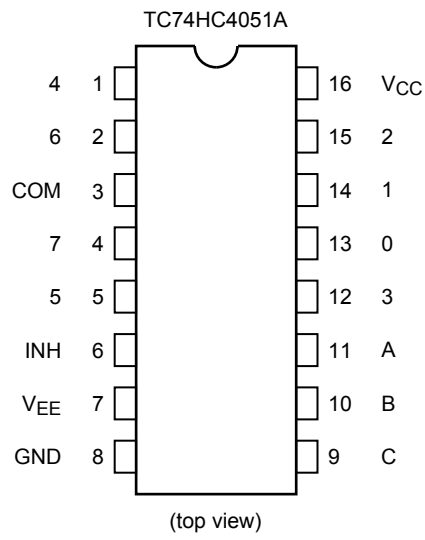
- High speed: t<sub>pd</sub> = 15 ns (typ.) at V<sub>CC</sub> = 5 V, V<sub>EE</sub> = 0 V
- Low power dissipation: I<sub>CC</sub> = 4 μA (max) at T<sub>a</sub> = 25°C
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Low ON resistance: R<sub>ON</sub> = 50 Ω (typ.) at V<sub>CC</sub> – V<sub>EE</sub> = 9 V
- High noise immunity: THD = 0.02% (typ.) at V<sub>CC</sub> – V<sub>EE</sub> = 9 V
- Pin and function compatible with 4051/4052/4053B



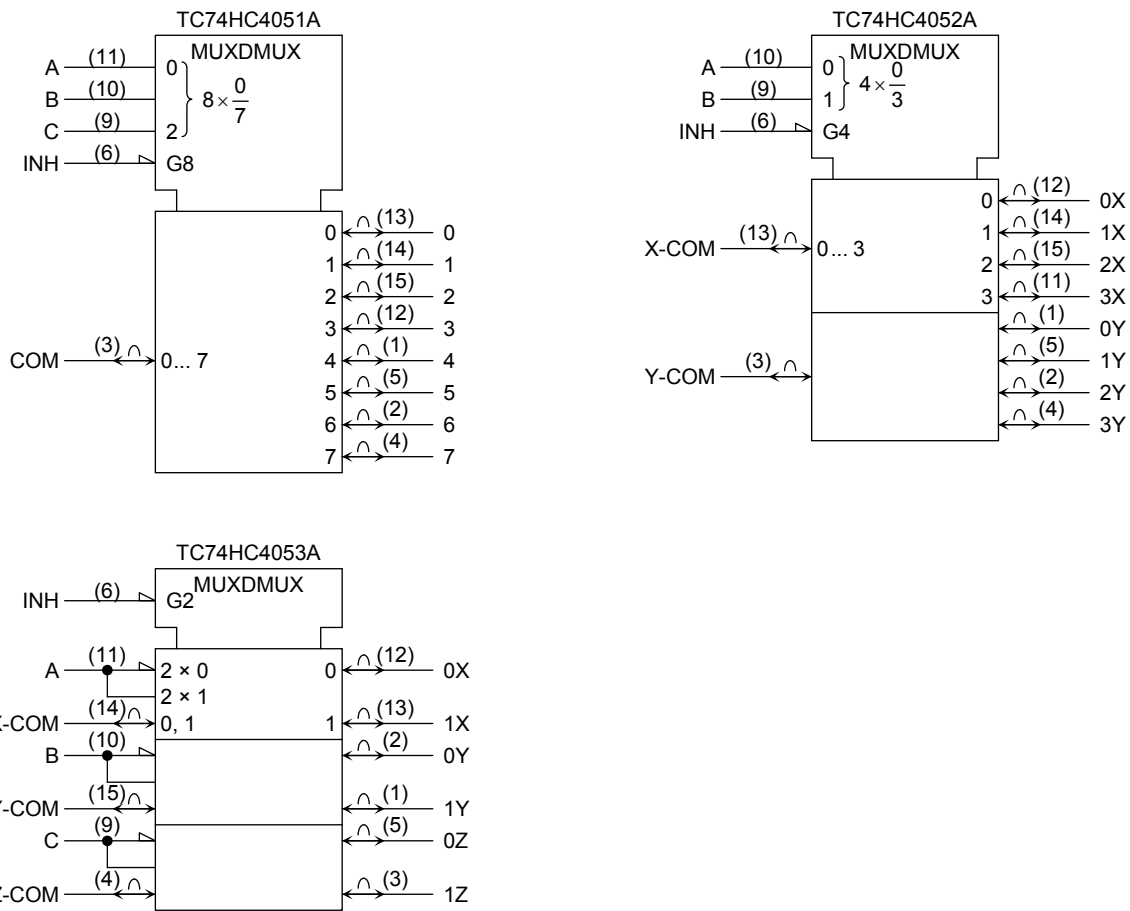
**Weight**

|                      |                 |
|----------------------|-----------------|
| DIP16-P-300-2.54A    | : 1.00 g (typ.) |
| SOP16-P-300-1.27A    | : 0.18 g (typ.) |
| TSSOP16-P-0044-0.65A | : 0.06 g (typ.) |

## Pin Assignment



## IEC Logic Symbol



## Truth Table

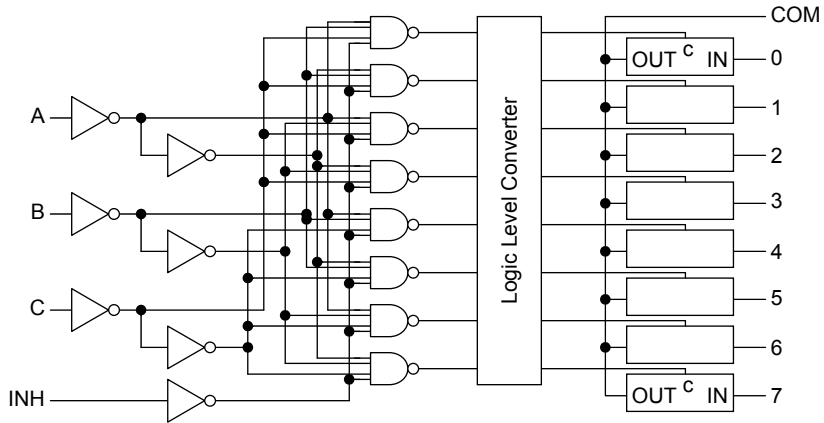
| Control Inputs |    |   |   | "ON" Channel |         |            |
|----------------|----|---|---|--------------|---------|------------|
| Inhibit        | C* | B | A | HC4051A      | HC4052A | HC4053A    |
| L              | L  | L | L | 0            | 0X, 0Y  | 0X, 0Y, 0Z |
| L              | L  | L | H | 1            | 1X, 1Y  | 1X, 0Y, 0Z |
| L              | L  | H | L | 2            | 2X, 2Y  | 0X, 1Y, 0Z |
| L              | L  | H | H | 3            | 3X, 3Y  | 1X, 1Y, 0Z |
| L              | H  | L | L | 4            | —       | 0X, 0Y, 1Z |
| L              | H  | L | H | 5            | —       | 1X, 0Y, 1Z |
| L              | H  | H | L | 6            | —       | 0X, 1Y, 1Z |
| L              | H  | H | H | 7            | —       | 1X, 1Y, 1Z |
| H              | X  | X | X | None         | None    | None       |

X: Don't care

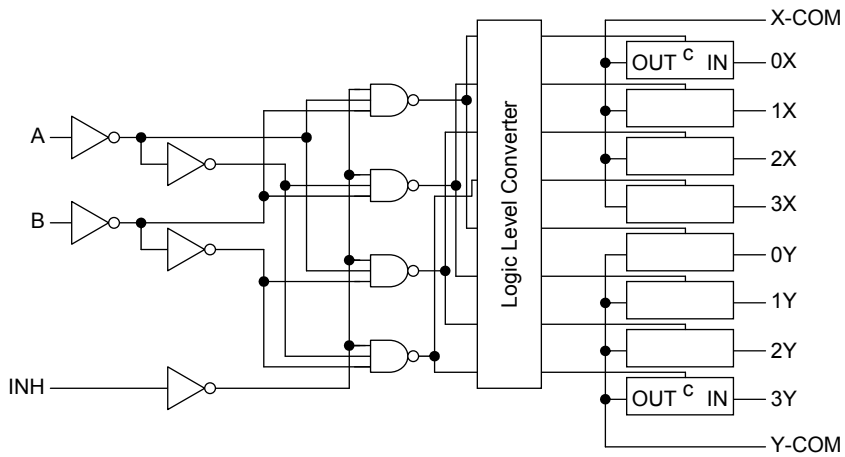
\*: Except HC4052A

**System Diagram**

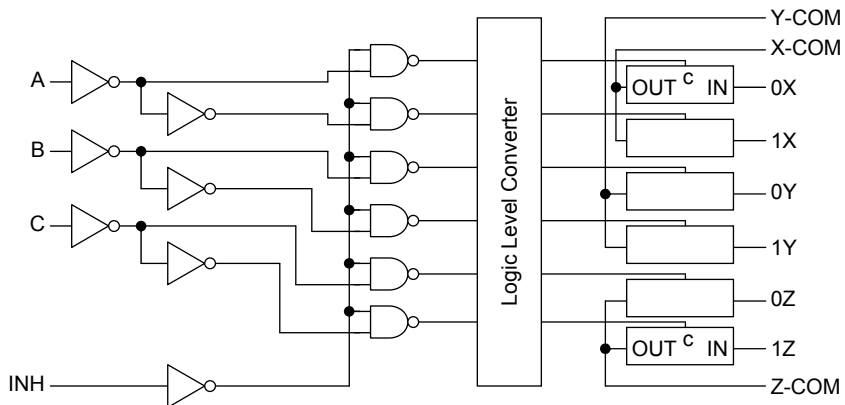
**TC74HC4051A**



**TC74HC4052A**



**TC74HC4053A**



## Absolute Maximum Ratings (Note 1)

| Characteristics               | Symbol          | Rating                              | Unit        |
|-------------------------------|-----------------|-------------------------------------|-------------|
| Supply voltage range          | $V_{CC}$        | -0.5 to 7                           | V           |
| Supply voltage range          | $V_{CC}-V_{EE}$ | -0.5 to 13                          | V           |
| Control input voltage         | $V_{IN}$        | -0.5 to $V_{CC} + 0.5$              | V           |
| Switch I/O voltage            | $V_{I/O}$       | $V_{EE} - 0.5$ to $V_{CC} + 0.5$    | V           |
| Control input diode current   | $I_{ICK}$       | $\pm 20$                            | mA          |
| I/O diode current             | $I_{OK}$        | $\pm 20$                            | mA          |
| Switch through current        | $I_T$           | $\pm 25$                            | mA          |
| DC $V_{CC}$ or ground current | $I_{CC}$        | $\pm 50$                            | mA          |
| Power dissipation             | $P_D$           | 500 (DIP) (Note 2)/180 (SOP, TSSOP) | mW          |
| Storage temperature           | $T_{stg}$       | -65 to 150                          | $^{\circ}C$ |

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of  $T_a = -40$  to  $65^{\circ}C$ . From  $T_a = 65$  to  $85^{\circ}C$  a derating factor of  $-10$  mW/ $^{\circ}C$  should be applied up to 300 mW.

## Operating Ranges (Note)

| Characteristics                  | Symbol          | Rating  | Unit        |
|----------------------------------|-----------------|---|-------------|
| Supply voltage range             | $V_{CC}$        | 2 to 6  | V           |
| Supply voltage range             | $V_{EE}$        | -6 to 0   | V           |
| Supply voltage range             | $V_{CC}-V_{EE}$ | 2 to 12   | V           |
| Control input voltage            | $V_{IN}$        | 0 to $V_{CC}$   | V           |
| Switch I/O voltage               | $V_{I/O}$       | $V_{EE}$ to $V_{CC}$  | V           |
| Operating temperature            | $T_{opr}$       | -40 to 85   | $^{\circ}C$ |
| Control input rise and fall time | $t_r, t_f$      | 0 to 1000 ( $V_{CC} = 2.0$ V)<br>0 to 500 ( $V_{CC} = 4.5$ V)<br>0 to 400 ( $V_{CC} = 6.0$ V) | ns          |

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused control inputs must be tied to either  $V_{CC}$  or GND.

## Electrical Characteristics

### DC Characteristics

| Characteristics                              | Symbol           | Test Condition   |  | Ta = 25°C       |  |     | Ta = -40 to 85°C |      | Unit  |    |
|--|------------------|--|--|-----------------|--|-----|------------------|------|-------|----|
|  |                  | V <sub>EE</sub> (V)  | V <sub>CC</sub> (V)                      | Min             | Typ.   | Max | Min              | Max  |       |    |
| High-level control input voltage             | V <sub>IHC</sub> | —  | —  | 2.0             | 1.50   | —   | —                | 1.50 | —     | V  |
|  |                  |  |  | 4.5             | 3.15   | —   | —                | 3.15 | —     |    |
|  |                  |  |  | 6.0             | 4.20   | —   | —                | 4.20 | —     |    |
| Low-level control input voltage              | V <sub>ILC</sub> | —  | —  | 2.0             | —  | —   | 0.50             | —    | 0.50  | V  |
|  |                  |  |  | 4.5             | —  | —   | 1.35             | —    | 1.35  |    |
|  |                  |  |  | 6.0             | —  | —   | 1.80             | —    | 1.80  |    |
| ON resistance                                | R <sub>ON</sub>  | V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub><br>V <sub>I/O</sub> = V <sub>CC</sub> to V <sub>EE</sub><br>I <sub>I/O</sub> ≤ 2 mA     | GND                                      | 4.5             | —  | 85  | 180              | —    | 225   | Ω  |
|  |                  |  | -4.5                                     | 4.5             | —  | 55  | 120              | —    | 150   |    |
|  |                  |  | -6.0                                     | 6.0             | —  | 50  | 100              | —    | 125   |    |
|  |                  | V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub><br>V <sub>I/O</sub> = V <sub>CC</sub> or V <sub>EE</sub><br>I <sub>I/O</sub> ≤ 2 mA     | GND                                      | 2.0             | —  | 150 | —                | —    | —     |    |
|  |                  |  | GND                                      | 4.5             | —  | 70  | 150              | —    | 190   |    |
|  |                  |  | -4.5                                     | 4.5             | —  | 50  | 100              | —    | 125   |    |
| Difference of ON resistance between switches | ΔR <sub>ON</sub> | V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub><br>V <sub>I/O</sub> = V <sub>CC</sub> to V <sub>EE</sub><br>I <sub>I/O</sub> ≤ 2 mA     | GND                                      | 4.5             | —  | 10  | 30               | —    | 35    | Ω  |
|  |                  |  | -4.5                                     | 4.5             | —  | 5   | 12               | —    | 15    |    |
|  |                  |  | -6.0                                     | 6.0             | —  | 5   | 10               | —    | 12    |    |
| Input/output leakage current (switch off)    | I <sub>OFF</sub> | V <sub>OS</sub> = V <sub>CC</sub> or GND<br>V <sub>IS</sub> = GND or V <sub>CC</sub><br>V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub> | GND                                      | 6.0             | —  | —   | ±60              | —    | ±600  | nA |
|  |                  |  | -6.0                                     | 6.0             | —  | —   | ±100             | —    | ±1000 |    |
|  |                  |  | Switch input leakage current (switch on) | I <sub>Iz</sub> | V <sub>OS</sub> = V <sub>CC</sub> or GND<br>V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub> | GND | 6.0              | —    | —     |    |
| -6.0   | 6.0              | —  |  |                 |  | —   | ±100             | —    | ±1000 |    |
| Control input current                        | I <sub>IN</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND   | GND                                      | 6.0             | —  | —   | ±0.1             | —    | ±1.0  | μA |
| Quiescent supply current                     | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND   | GND                                      | 6.0             | —  | —   | 4.0              | —    | 40.0  | μA |
|  |                  |  | -6.0                                     | 6.0             | —  | —   | 8.0              | —    | 80.0  |    |

## AC Characteristics (C<sub>L</sub> = 50 pF, input: t<sub>r</sub> = t<sub>f</sub> = 6 ns, GND = 0 V)

| Characteristics                           | Symbol                               | Test Condition |      | Ta = 25°C           |                     |      | Ta = -40 to 85°C |     | Unit |     |
|---|--------------------------------------|----------------|------|---------------------|---------------------|------|------------------|-----|------|-----|
|   |                                      |                |      | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min  | Typ.             | Max |      | Min |
| Phase difference between input and output | φ <sub>I/O</sub>                     | All types      | GND  | 2.0                 | —                   | 25   | 60               | —   | 75   | ns  |
|   |                                      |                | GND  | 4.5                 | —                   | 6    | 12               | —   | 15   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 5    | 10               | —   | 13   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 4    | —                | —   | —    |     |
| Output enable time                        | t <sub>pZL</sub><br>t <sub>pZH</sub> | 4051 (Note 1)  | GND  | 2.0                 | —                   | 64   | 225              | —   | 280  | ns  |
|   |                                      |                | GND  | 4.5                 | —                   | 18   | 45               | —   | 56   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 15   | 38               | —   | 48   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 18   | —                | —   | —    |     |
|   |                                      | 4052 (Note 1)  | GND  | 2.0                 | —                   | 64   | 225              | —   | 280  |     |
|   |                                      |                | GND  | 4.5                 | —                   | 18   | 45               | —   | 56   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 15   | 38               | —   | 48   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 18   | —                | —   | —    |     |
|   |                                      | 4053 (Note 1)  | GND  | 2.0                 | —                   | 50   | 225              | —   | 280  |     |
|   |                                      |                | GND  | 4.5                 | —                   | 14   | 45               | —   | 56   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 12   | 38               | —   | 48   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 14   | —                | —   | —    |     |
| Output disable time                       | t <sub>pLZ</sub><br>t <sub>pHZ</sub> | 4051 (Note 1)  | GND  | 2.0                 | —                   | 100  | 250              | —   | 315  | ns  |
|   |                                      |                | GND  | 4.5                 | —                   | 33   | 50               | —   | 63   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 28   | 43               | —   | 54   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 29   | —                | —   | —    |     |
|   |                                      | 4052 (Note 1)  | GND  | 2.0                 | —                   | 100  | 250              | —   | 315  |     |
|   |                                      |                | GND  | 4.5                 | —                   | 33   | 50               | —   | 63   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 28   | 43               | —   | 54   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 29   | —                | —   | —    |     |
|   |                                      | 4053 (Note 1)  | GND  | 2.0                 | —                   | 95   | 225              | —   | 280  |     |
|   |                                      |                | GND  | 4.5                 | —                   | 30   | 45               | —   | 56   |     |
|   |                                      |                | GND  | 6.0                 | —                   | 26   | 38               | —   | 48   |     |
|   |                                      |                | -4.5 | 4.5                 | —                   | 26   | —                | —   | —    |     |
| Control input capacitance                 | C <sub>IN</sub>                      | All types      | —    | —                   | —                   | 5    | 10               | —   | 10   | pF  |
| COMMON terminal capacitance               | C <sub>IS</sub>                      | 4051           | —    | —                   | —                   | 36   | 70               | —   | 70   | pF  |
|   |                                      | 4052           | -5.0 | 5.0                 | —                   | 19   | 40               | —   | 40   |     |
|   |                                      | 4053           | —    | —                   | —                   | 11   | 20               | —   | 20   |     |
| SWITCH terminal capacitance               | C <sub>OS</sub>                      | 4051           | —    | —                   | —                   | 7    | 15               | —   | 15   | pF  |
|   |                                      | 4052           | -5.0 | 5.0                 | —                   | 7    | 15               | —   | 15   |     |
|   |                                      | 4053           | —    | —                   | —                   | 7    | 15               | —   | 15   |     |
| Feedthrough capacitance                   | C <sub>IOS</sub>                     | 4051           | —    | —                   | —                   | 0.95 | 2                | —   | 2    | pF  |
|   |                                      | 4052           | -5.0 | 5.0                 | —                   | 0.85 | 2                | —   | 2    |     |
|   |                                      | 4053           | —    | —                   | —                   | 0.75 | 2                | —   | 2    |     |
| Power dissipation capacitance             | C <sub>PD</sub>                      | 4051           | —    | —                   | —                   | 70   | —                | —   | —    | pF  |
|   |                                      | 4052 (Note 2)  | GND  | 5.0                 | —                   | 71   | —                | —   | —    |     |
|   |                                      | 4053           | —    | —                   | —                   | 67   | —                | —   | —    |     |

Note 1: R<sub>L</sub> = 1 kΩ

Note 2: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance of IC which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

## Analog Switch Characteristics (GND = 0 V, Ta = 25°C) (Note 1)

| Characteristics                               | Symbol           | Test Condition  |  |                        | Typ.   | Unit  |     |              |      |     |    |
|---|------------------|---|--|------------------------|--|-------|-----|--------------|------|-----|----|
|   |                  |   | V <sub>EE</sub><br>(V)                   | V <sub>CC</sub><br>(V) |  |       |     |              |      |     |    |
| Sine wave distortion<br>(T.H.D)               |                  | R <sub>L</sub> = 10 kΩ,<br>C <sub>L</sub> = 50 pF<br>f <sub>IN</sub> = 1 kHz  | V <sub>IN</sub> = 4.0 V <sub>p-p</sub>   | -2.25                  | 2.25   | 0.025 | %   |              |      |     |    |
|   |                  |   | V <sub>IN</sub> = 8.0 V <sub>p-p</sub>   | -4.5                   | 4.5  | 0.020 |     |              |      |     |    |
|   |                  |   | V <sub>IN</sub> = 11.0 V <sub>p-p</sub>  | -6.0                   | 6.0  | 0.018 |     |              |      |     |    |
| Frequency response<br>(switch on)             | f <sub>max</sub> | Adjust f <sub>IN</sub> voltage to obtain<br>0dBm at V <sub>OS</sub><br>Increase f <sub>IN</sub> frequency until<br>dB meter reads -3dB<br>R <sub>L</sub> = 50 Ω, C <sub>L</sub> = 10 pF<br>f <sub>IN</sub> = 1 MHz, sine wave | All (Note 2)                             | -2.25                  | 2.25   | 120   | MHz |              |      |     |    |
|   |                  |   | 4051 (Note 3)                            |                        |  | 45    |     |              |      |     |    |
|   |                  |   | 4052                                     |                        |  | 70    |     |              |      |     |    |
|   |                  |   | 4053                                     | 95                     | -4.5   | 4.5   |     | All (Note 2) | 190  |     |    |
|   |                  |   | 4051 (Note 3)                            | 70                     |  |       |     |              |      |     |    |
|   |                  |   | 4052                                     | 110                    |  |       |     |              |      |     |    |
|   |                  |   | 4053                                     | 150                    | -6.0   | 6.0   |     | All (Note 2) | 200  |     |    |
|   |                  |   | 4051 (Note 3)                            | 85                     |  |       |     |              |      |     |    |
|   |                  |   | 4052                                     | 140                    |  |       |     |              |      |     |    |
|   |                  |   | 4053                                     | 190                    |  |       |     |              |      |     |    |
|   |                  |   | Feed through attenuation<br>(switch off) |                        | V <sub>IN</sub> is centered at (V <sub>CC</sub> - V <sub>EE</sub> )/2<br>Adjust input for 0dBm<br>R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF<br>f <sub>IN</sub> = 1 MHz, sine wave |       |     | -2.25        | 2.25 | -50 | dB |
|   |                  |   |  |                        |  |       |     | -4.5         | 4.5  | -50 |    |
|   | -6.0             | 6.0   |  |                        |  | -50   |     |              |      |     |    |
| Crosstalk<br>(control input to signal output) |                  | R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF<br>f <sub>IN</sub> = 1 MHz, square wave (t <sub>r</sub> = t <sub>f</sub> = 6 ns)   |  | -2.25                  | 2.25   | 60    | mV  |              |      |     |    |
|   |                  |   |  | -4.5                   | 4.5  | 140   |     |              |      |     |    |
|   |                  |   |  | -6.0                   | 6.0  | 200   |     |              |      |     |    |
| Crosstalk<br>(between any switches)           |                  | Adjust V <sub>IN</sub> to obtain 0dBm at input<br>R <sub>L</sub> = 600 Ω, C <sub>L</sub> = 50 pF<br>f <sub>IN</sub> = 1 MHz, sine wave  |  | -2.25                  | 2.25   | -50   | dB  |              |      |     |    |
|   |                  |   |  | -4.5                   | 4.5  | -50   |     |              |      |     |    |
|   |                  |   |  | -6.0                   | 6.0  | -50   |     |              |      |     |    |

Note 1: These characteristics are determined by design of devices.

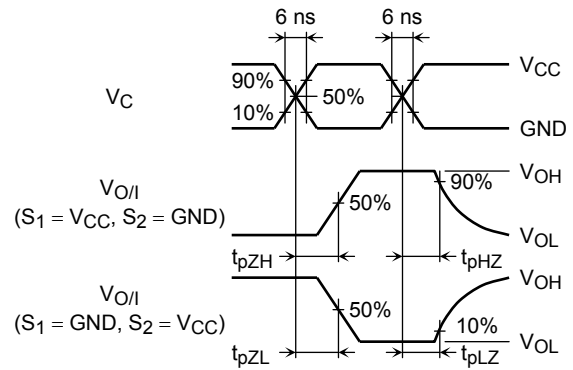
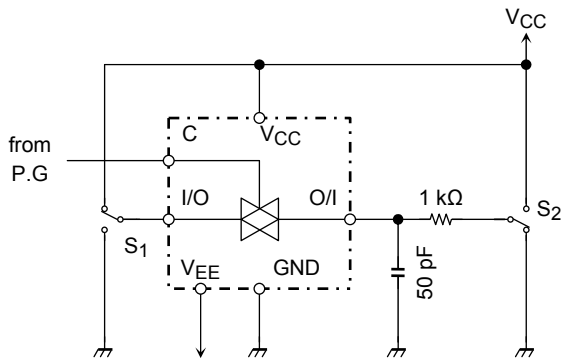
Note 2: Input COMMON terminal, and measured at SWITCH terminal.

Note 3: Input SWITCH terminal, and measured at COMMON terminal.

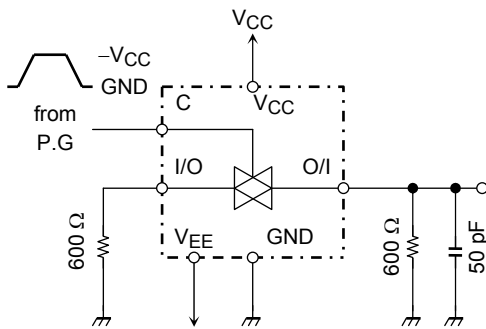


## Switching Characteristics Test Circuits

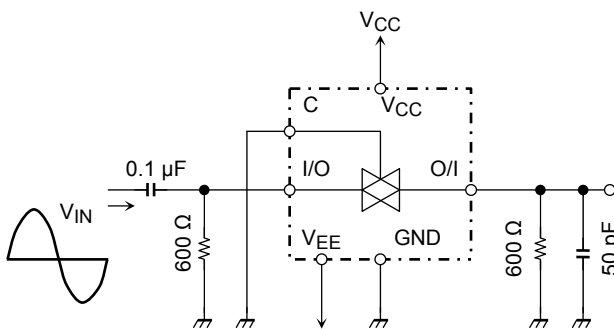
### 1. $t_{pLZ}$ , $t_{pHZ}$ , $t_{pZL}$ , $t_{pZH}$



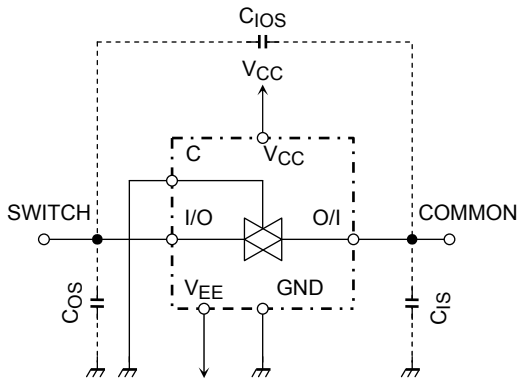
### 2. Cross Talk (control input-switch output) $f_{IN} = 1$ MHz duty = 50% $t_r = t_f = 6$ ns



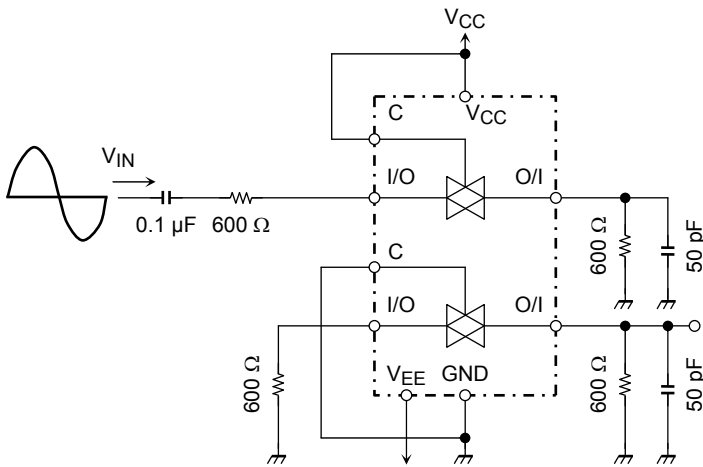
### 3. Feedthrough Attenuation



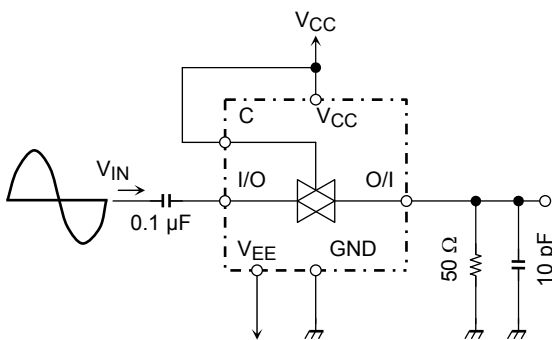
**4. C<sub>IOS</sub>, C<sub>IS</sub>, C<sub>OS</sub>**



**5. Cross Talk (between any two switches)**



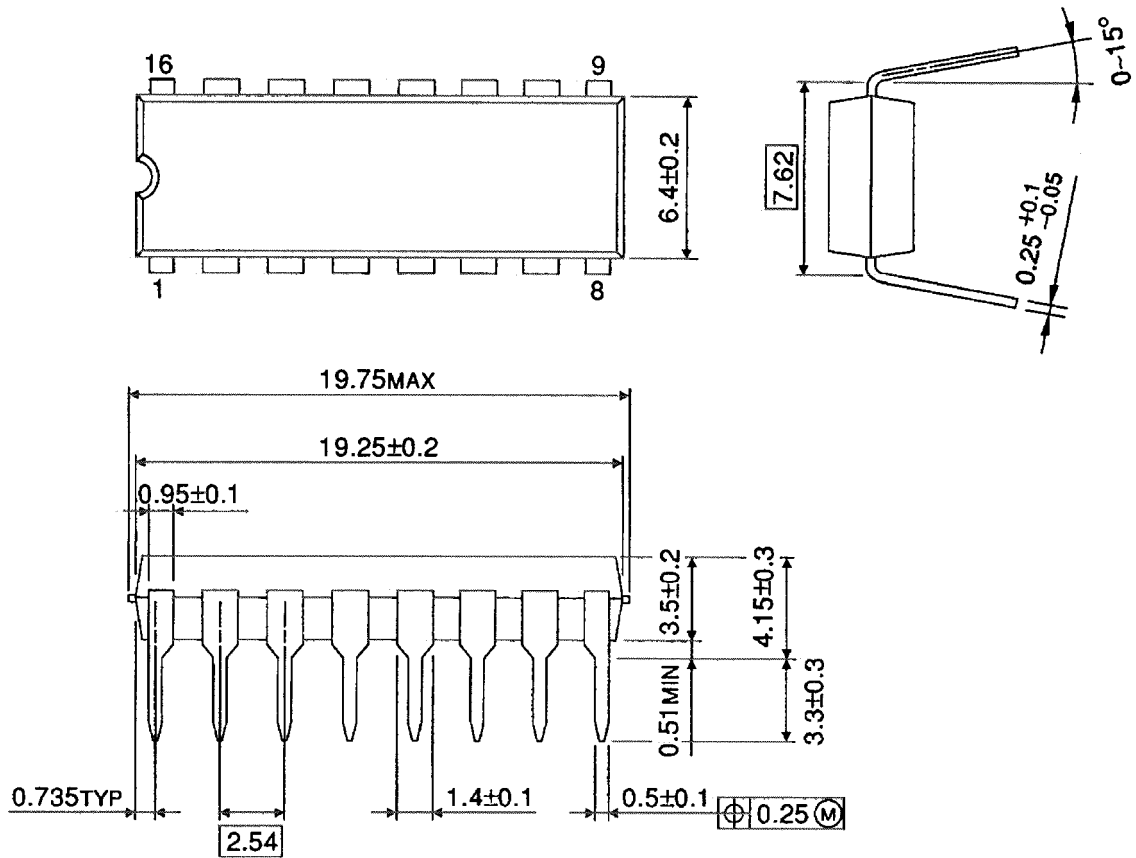
**6. Frequency Response (switch on)**



## Package Dimensions

DIP16-P-300-2.54A

Unit : mm

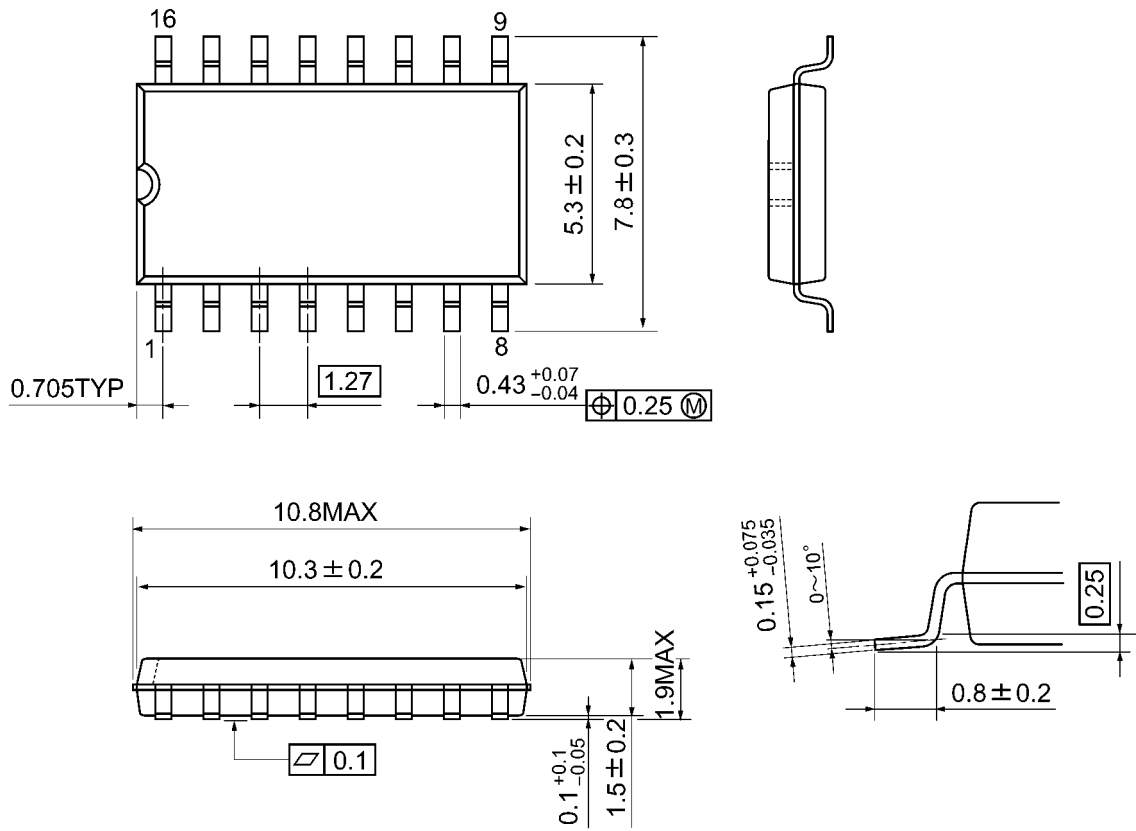


Weight: 1.00 g (typ.)

**Package Dimensions**

SOP16-P-300-1.27A

Unit: mm

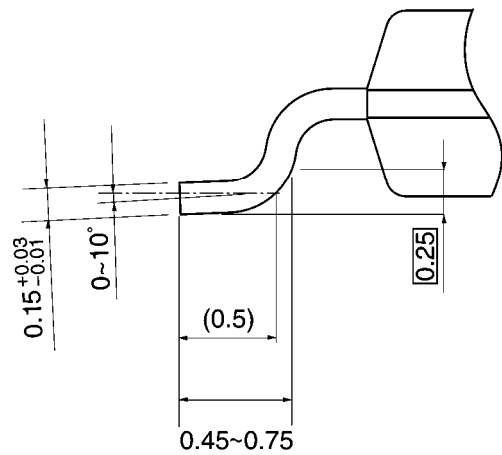
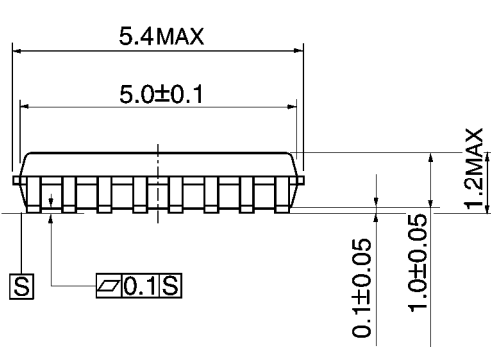
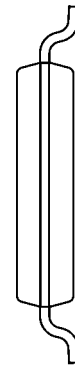
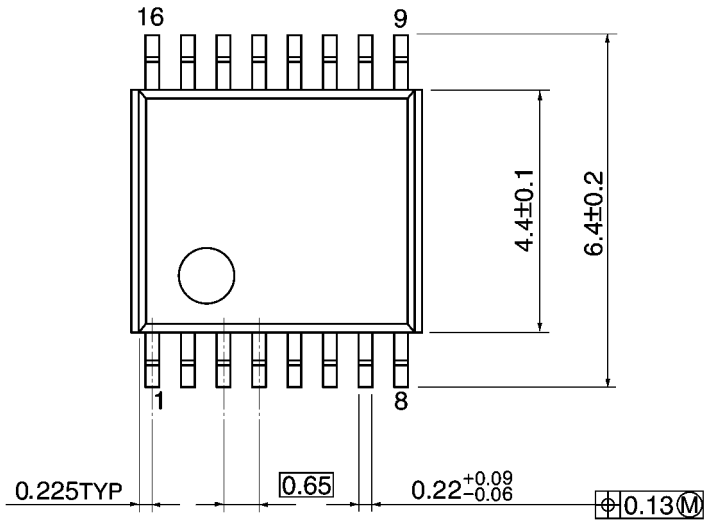


Weight: 0.18 g (typ.)

**Package Dimensions**

TSSOP16-P-0044-0.65A

Unit: mm



Weight: 0.06 g (typ.)

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